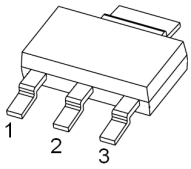
GOOD-ARK
SEMICONDUCTOR

PZT3906
PNP Transistor

Features

- Low voltage and low current
- Complementary to PZT3904
- General purpose amplifier and switch application



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1. BASE
2. COLLECTOR
3. EMITTER

Absolute Maximum Ratings (T_A = 25 °C unless otherwise noted)

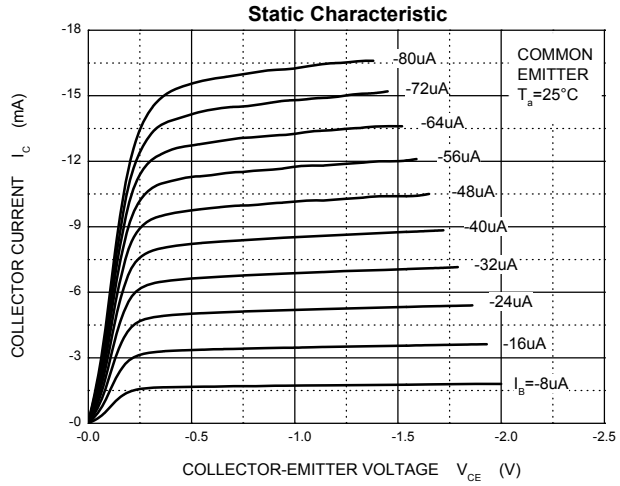
Parameter	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-40	V
Collector-Emitter Voltage	V_{CEO}	-40	V
Emitter-Base Voltage	V_{EBO}	-5	V
Collector Current	I_C	-200	mA
Collector Power Dissipation	P_C	1	W
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	125	℃/W
Junction Temperature	T_J	-55 to +150	℃
Storage Temperature	T_{STG}	-55 to +150	℃

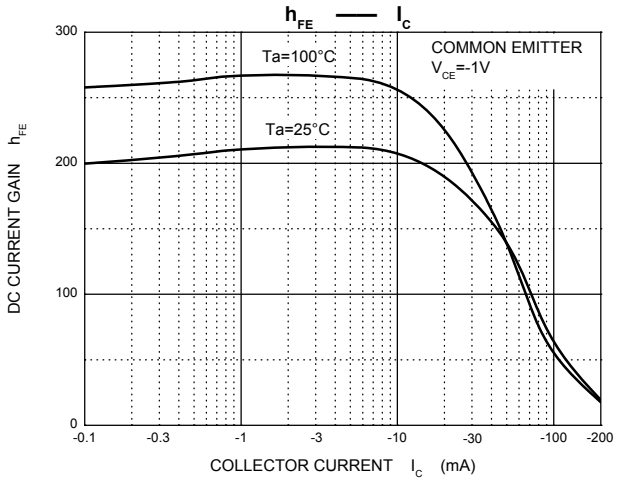
Electrical Characteristics (T_A = 25 °C unless otherwise noted)

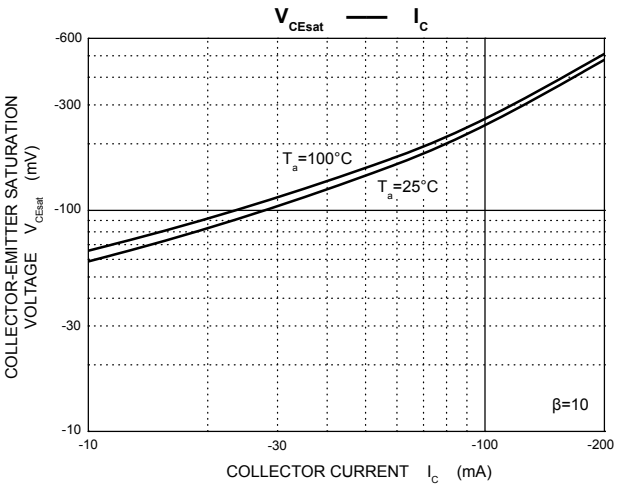
Parameter	Symbol	Test Conditions	Min	Max	Unit
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$*	I_C=-0.01mA,I_E=0	-40	-	V
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$*	I_C=-1mA,I_B=0	-40	-	V
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$*	I_E=0.01mA,I_C=0	-5	-	V
Collector Cut-Off Current	I_{CBO}	V_{CB}=-30V,I_E=0	-	-50	nA
Collector Cut-Off Current	I_{CEO}	V_{CE}=-30V, I_C=0	-	-500	nA
Collector Cut-Off Current	I_{CEX}	V_{CE}=-30V, $V_{BE(off)}$=-3V	-	-50	nA
DC Current Gain	$h_{FE(1)}$*	V_{CE}=-1V, I_C=-0.1mA	60	-	-
	$h_{FE(2)}$	V_{CE}=-1V, I_C=-1mA	80	-	-
	$h_{FE(3)}$	V_{CE}=-1V, I_C=-10mA	100	300	-
	$h_{FE(4)}$	V_{CE}=-1V, I_C=-50mA	60	-	-
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$*	I_C=-10mA,I_B=-1mA	-	-0.25	V
		I_C=-50mA,I_B=-5mA	-	-0.4	V
Base-Emitter Saturation Voltage	$V_{BE(sat)}$*	I_C=-10mA,I_B=-1mA	-0.65	-0.85	V
		I_C=-50mA,I_B=-5mA	-	-0.95	V
Transition Frequency	f_T	V_{CE}=-20V,I_C=-10mA, f=100MHz	250	-	MHz
Collector Output Capacitance	C_{ob}	V_{CB}=-5V, I_E=0, f=1MHz	-	4.5	pF
Emitter Input Capacitance	C_{ib}	V_{BE}=-0.5V, I_C=0, f=1MHz	-	10	pF
Delay Time	t_d	V_{CC}=-3V, $V_{BE(off)}$=-0.5V I_C=-10mA,	-	35	nS
Rise Time	t_r	I_{B1}= -I_{B2}=-1mA	-	35	
Storage Time	t_s	V_{CC}=-3V, I_C=-10mA,	-	225	nS
Fall Time	t_f	I_{B1}=-I_{B2}=-1mA	-	75	

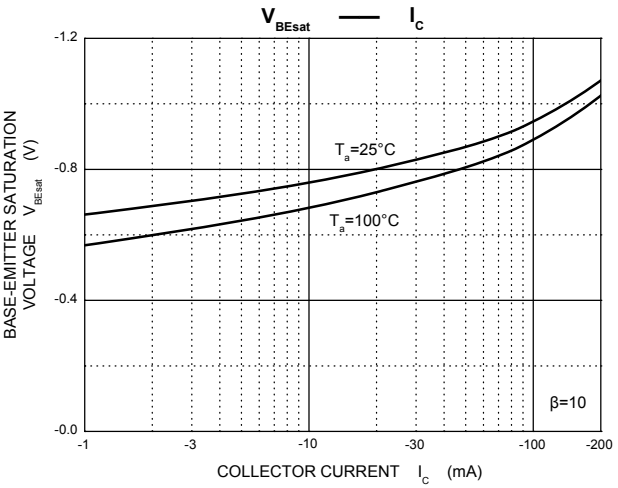
*Pulse test: pulse width ≤300μS, duty cycle≤ 2.0%.

Typical Characteristic Curves

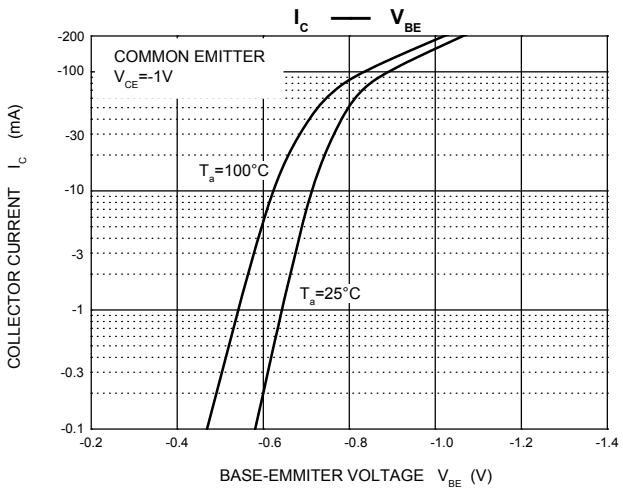


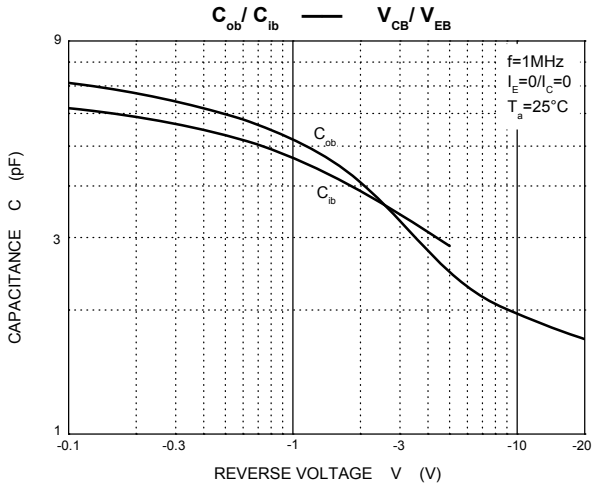


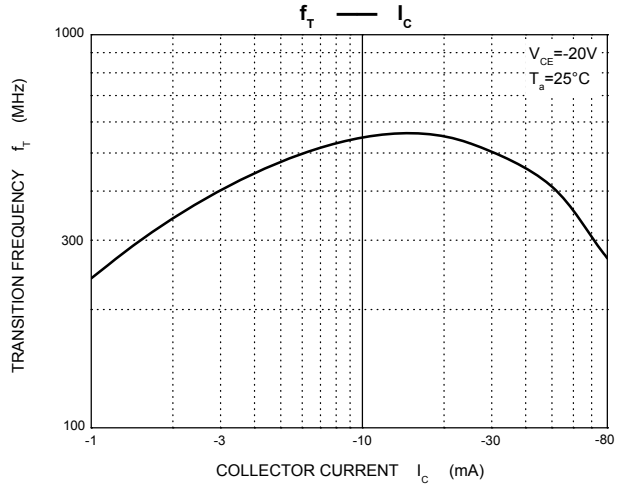


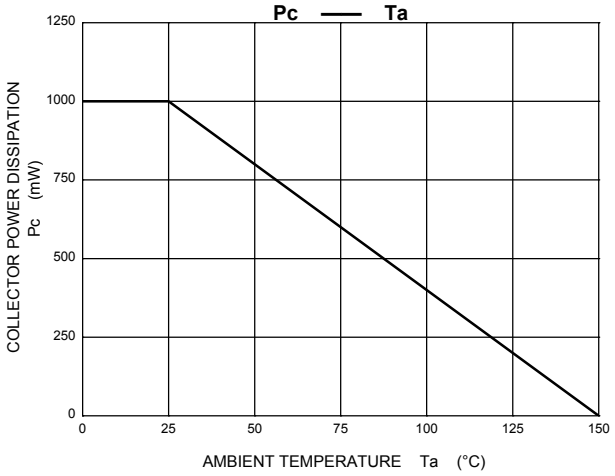


Typical Characteristic Curves









Package Outline Dimensions

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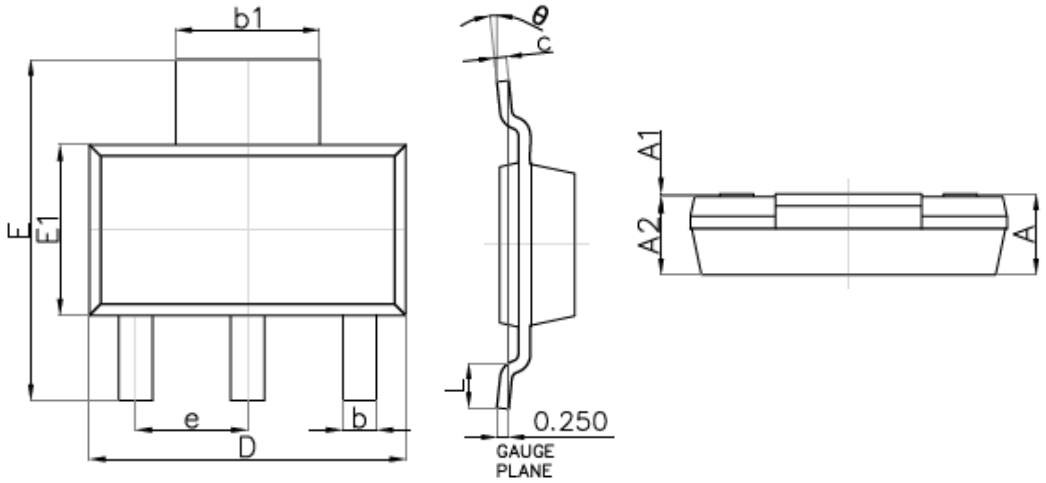
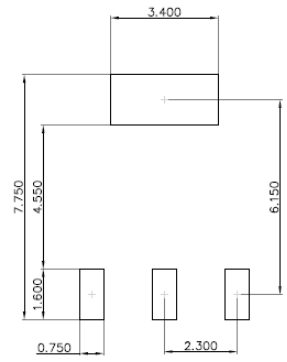


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	——	1.800	——	0.071
A1	0.020	0.100	0.001	0.004
A2	1.500	1.700	0.059	0.067
b	0.660	0.840	0.026	0.033
b1	2.900	3.100	0.114	0.122
c	0.230	0.350	0.009	0.014
D	6.300	6.700	0.248	0.264
E	6.700	7.300	0.264	0.287
E1	3.300	3.700	0.130	0.146
e	2.300(BSC)		0.091(BSC)	
L	0.750	——	0.030	——
θ	0°	10°	0°	10°

Suggested Pad Layout



Note:
1.Controlling dimension:in millimeters.
2.General tolerance:±0.050mm.
3.The pad layout is for reference purposes only.

Ordering Information

Device	Package	Marking	Quantity	HSF Status
PZT3906	SOT-223	ZT3906	1000pcs / Reel	RoHS Compliant